



11-30-dcf

CNC

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No. : 09/540,288  
Applicant : Wu et al.  
Filed : March 31, 2000  
Title : Electroluminescent Laminate with Patterned Phosphor Structure and  
Thick Film Dielectric with Improved Dielectric Properties  
Patent No. : 6,771,019  
Issued : August 3, 2004  
Docket No. : 36-00

## CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as Express Mail in an envelope addressed to: Mail Stop Certificate of Correction Branch, Hon. Commissioner for Patents, PO Box 1450, Alexandria VA 22313-1450 EV 584 577 859 US

29 Nov 04  
DateKay Speaker  
Kay Speaker

## REQUEST FOR CERTIFICATE OF CORRECTION

Hon. Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

Certificate  
DEC 02 2004

## of Correction

A Certificate of Correction for U.S. Patent 6,771,019 B1, issued August 3, 2004, is respectfully requested as the printed patent contains errors that affect the clarity of the patent.

Two copies of PTO form 1050 are enclosed herewith listing the corrections requested. These corrections are discussed in detail below. All of the corrections were previously introduced as part of the Amendment filed November 14, 2003, and were accepted by the Examiner in the Notice of Allowability mailed December 8, 2003. Specifically, claims 243, 265, 275, 282, 286, 288, 310, 320, 331 and 604 (now issued claims 1, 34, 38, 20, 24, 44, 128, 132, 83 and 89) were amended. Despite acceptance of the amendments to the claims by the Examiner, the Patent Office did not include the amendments in the printed patent. No new matter has been added.

DEC 8 2004

On column 41, claim 1, line 32, please insert --, said at least first and second phosphor deposits being formed from phosphors of different host materials-- after "phosphor deposits". Support for this correction can be found on page 2, claim 243, of the Amendment filed November 14, 2003.

On column 43, claim 20, line 30, please replace "a threshold voltage adjustment layer selected" with --the threshold voltage adjustment layer being selected--. Support for this correction can be found on page 7, claim 282, of the Amendment filed November 14, 2003.

On column 43, claim 24, line 61, please replace "a threshold voltage adjustment layer selected" with --the threshold voltage adjustment layer being selected--. Support for this correction can be found on page 7, claim 286, of the Amendment filed November 14, 2003.

On column 44, claim 34, line 51, please replace "a threshold voltage" with --the threshold voltage--. Support for this correction can be found on page 5, claim 265, of the Amendment filed November 14, 2003.

On column 45, claim 38, lines 3-4, please replace "a threshold voltage adjustment layer selected" with --the threshold voltage adjustment layer being selected--. Support for this correction can be found on page 6, claim 275, of the Amendment filed November 14, 2003.

On column 45, claim 44, line 64, after "dielectric layer", please insert --, S is the dielectric strength of the dielectric layer--. Support for this correction can be found on page 8, claim 288, of the Amendment filed November 14, 2003.

On column 49, claim 83, line 30, please replace "a threshold voltage adjustment layer selected" with --the threshold voltage adjustment layer being selected--. Support for

this correction can be found on page 13, claim 331, of the Amendment filed November 14, 2003.

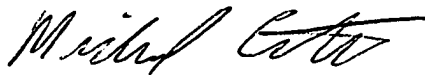
On column 49, claim 89, line 56 please replace "a thickness" and replace with --the thickness--. On line 59, after "dielectric layer", please insert --, S is the dielectric strength of the dielectric layer--. Support for this correction can be found on pages 17-18, claim 604, of the Amendment filed November 14, 2003.

On column 52, claim 128, lines 12-13, please replace "a threshold voltage" with --the threshold voltage--. Support for this correction can be found on page 11, claim 310, of the Amendment filed November 14, 2003.

On column 52, claim 132, lines 29-30, please replace "a threshold voltage adjustment layer selected" with --the threshold voltage adjustment layer being selected--. Support for this correction can be found on page 12, claim 320, of the Amendment filed November 14, 2003.

It is believed that no fee is required with this submission as the errors are the result of a mistake by the Patent Office. If a fee is required, please charge any deficiency or credit any overpayment to Deposit Account No. 07-1969.

Respectfully submitted,



Michael J. Curtis  
Reg. No. 54,053  
Customer No. 23713

Greenlee, Winner and Sullivan, P.C.  
4875 Pearl East Circle, Suite 200  
Boulder, CO 80301  
Phone: (303) 499-8080; FAX: (303) 499-8089  
Email: [Winner@Greenwin.com](mailto:Winner@Greenwin.com)  
Attorney Docket No. 36-00  
ks: November 29, 2004

UNITED STATES PATENT AND TRADEMARK OFFICE  
CERTIFICATE OF CORRECTION

PATENT NO. : 6,771,019 B1

DATED : Aug. 3, 2004

INVENTOR(S) : Wu et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 41

Claim 1, line 32, after "phosphor deposits" insert --, said at least first and second phosphor deposits being formed from phosphors of different host materials--.

Column 43

Claim 20, line 30, delete "a threshold voltage adjustment layer selected" and replace with --the threshold voltage adjustment layer being selected--.

Claim 24, line 61 delete "a threshold voltage adjustment layer selected" and replace with --the threshold voltage adjustment layer being selected--.

Column 44

Claim 34, line 51, delete "a threshold voltage" and replace with --the threshold voltage--.

Column 45

Claim 38, lines 3-4, delete "a threshold voltage adjustment layer selected" and replace with --the threshold voltage adjustment layer being selected--.

Claim 44, line 64, after "dielectric layer" insert --, S is the dielectric strength of the dielectric layer--.

Column 49

Claim 83, line 30, delete "a threshold voltage adjustment layer selected" and replace with --the threshold voltage adjustment layer being selected--.

Claim 89, line 56, delete "a thickness" and replace with --the thickness--.

Claim 89, line 59, after "dielectric layer" insert --, S is the dielectric strength of the dielectric layer--.

Column 52

Claim 128, lines 12-13, delete "a threshold voltage" and replace with --the threshold voltage--.

Claim 132, lines 29-30, delete "a threshold voltage adjustment layer selected" and replace with --the threshold voltage adjustment layer being selected--.

MAILING ADDRESS OF SENDER:

PATENT NO. US 6,771,019 B1

GREENLEE, WINNER and SULLIVAN, P.C.

4875 Pearl East Circle, Suite 200

Boulder, CO 80301

Phone: (303) 499-8080

Fax: (303) 499-8089

email: winner@greenwin.com

No. of add'l copies  
@ \$.30 per page

FORM PTO 1050 (REV. 3-82)

8 DEC 2004

UNITED STATES PATENT AND TRADEMARK OFFICE  
CERTIFICATE OF CORRECTION

PATENT NO. : 6,771,019 B1

DATED : Aug. 3, 2004

INVENTOR(S) : Wu et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 41

Claim 1, line 32, after "phosphor deposits" insert --, said at least first and second phosphor deposits being formed from phosphors of different host materials--.

Column 43

Claim 20, line 30, delete "a threshold voltage adjustment layer selected" and replace with --the threshold voltage adjustment layer being selected--.

Claim 24, line 61 delete "a threshold voltage adjustment layer selected" and replace with --the threshold voltage adjustment layer being selected--.

Column 44

Claim 34, line 51, delete "a threshold voltage" and replace with --the threshold voltage--.

Column 45

Claim 38, lines 3-4, delete "a threshold voltage adjustment layer selected" and replace with --the threshold voltage adjustment layer being selected--.

Claim 44, line 64, after "dielectric layer" insert --, S is the dielectric strength of the dielectric layer--.

Column 49

Claim 83, line 30, delete "a threshold voltage adjustment layer selected" and replace with --the threshold voltage adjustment layer being selected--.

Claim 89, line 56, delete "a thickness" and replace with --the thickness--.

Claim 89, line 59, after "dielectric layer" insert --, S is the dielectric strength of the dielectric layer--.

Column 52

Claim 128, lines 12-13, delete "a threshold voltage" and replace with --the threshold voltage--.

Claim 132, lines 29-30, delete "a threshold voltage adjustment layer selected" and replace with --the threshold voltage adjustment layer being selected--.

MAILING ADDRESS OF SENDER:

PATENT NO. US 6,771,019 B1

GREENLEE, WINNER and SULLIVAN, P.C.  
4875 Pearl East Circle, Suite 200  
Boulder, CO 80301  
Phone: (303) 499-8080  
Fax: (303) 499-8089  
email: winner@greenwin.com

No. of add'l copies  
@ \$.30 per page

FORM PTO 1050 (REV. 3-82)

8 DEC 2004